

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|-------------------------------|----------------------------------------------|
| | 1.5Ω @ V _{GS} = 4.5V | 0.40A |
| 30V | 2.0Ω @ V _{GS} = 2.5V | 0.35A |
| | 3.0Ω @ V _{GS} = 1.8V | 0.28A |
| | 4.5Ω @ V _{GS} = 1.5V | 0.23A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- Analog Switch

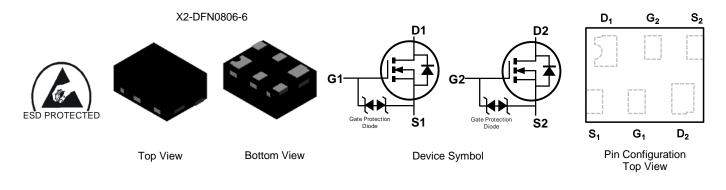
Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surface Mount Package 0.8mm x 0.6mm
- ESD Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- The DMN31D5UDAQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Case: X2-DFN0806-6
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Annealed over Copper Lead-Frame. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.001 grams (Approximate)



Ordering Information (Note 4)

| Part Number | Case | Packaging |
|----------------|--------------|--------------------|
| DMN31D5UDAQ-7B | X2-DFN0806-6 | 10,000/Tape & Reel |

 Notes:
 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



B7 = Product Type Marking Code

Top View



Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

| Characteristic | | | Symbol | Value | Unit |
|--------------------------------------------------------|-----------------|--------------------------------------------------|------------------|-------------|------|
| Drain-Source Voltage | | | V _{DSS} | 30 | V |
| Gate-Source Voltage | | | V _{GSS} | ±12 | V |
| Continuous Drain Current (Note 5) V_{GS} = 4.5V | Steady State | T _A = +25°C T _A = +70°C | ID | 0.4 0.32 | A |
| Maximum Continuous Body Diode Forward Current (Note 6) | | | ls | 0.8 | A |
| Pulsed Drain Current (Note 6) | | | I _{DM} | 0.8 | А |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--------------------------------------------------|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 0.37 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 339 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--------------------------------------------------------|---------------------|-----|------|-----|------|--------------------------------------------------------------|--|
| DFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | | 30 | | _ | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current @ $T_C = +25^{\circ}C$ | I _{DSS} | | | 100 | nA | $V_{DS} = 24V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | | | ±10 | μA | $V_{GS} = \pm 10V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.4 | _ | 1.0 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| | | - | 1.2 | 1.5 | Ω | $V_{GS} = 4.5V, I_D = 100mA$ | |
| Static Drain-Source On-Resistance | Б | _ | 1.3 | 2.0 | | $V_{GS} = 2.5V, I_D = 50mA$ | |
| | R _{DS(ON)} | _ | 1.5 | 3.0 | | $V_{GS} = 1.8V, I_D = 20mA$ | |
| | | — | 1.8 | 4.5 | | $V_{GS} = 1.5V, I_D = 10mA$ | |
| Diode Forward Voltage | | _ | 0.6 | 1.0 | V | $V_{GS} = 0V, I_{S} = 10mA$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | - | |
| Input Capacitance | | | 22.6 | _ | pF | | |
| Output Capacitance | | - | 2.68 | — | pF | V _{DS} = 15V, V _{GS} = 0V, f = 1.0MHz | |
| Reverse Transfer Capacitance | C _{rss} | - | 1.8 | — | pF | | |
| Total Gate Charge | | _ | 0.38 | _ | nC | | |
| Gate-Source Charge | | _ | 0.05 | _ | nC | V _{GS} = 4.5V, V _{DS} = 15V, In = 200mA | |
| Gate-Drain Charge | Q _{gd} | _ | 0.07 | _ | nC | $-I_D = 200 \text{mA}$ | |
| Turn-On Delay Time | t _{D(ON)} | _ | 3.2 | _ | ns | | |
| Turn-On Rise Time | t _R | _ | 2.2 | _ | ns | V _{DD} = 15V, V _{GS} = 4.5V, | |
| Turn-Off Delay Time Turn-Off Fall Time | | _ | 21 | _ | ns | $R_G = 2\Omega, I_D = 200 \text{mA}$ | |
| | | | 7.5 | — | ns | | |

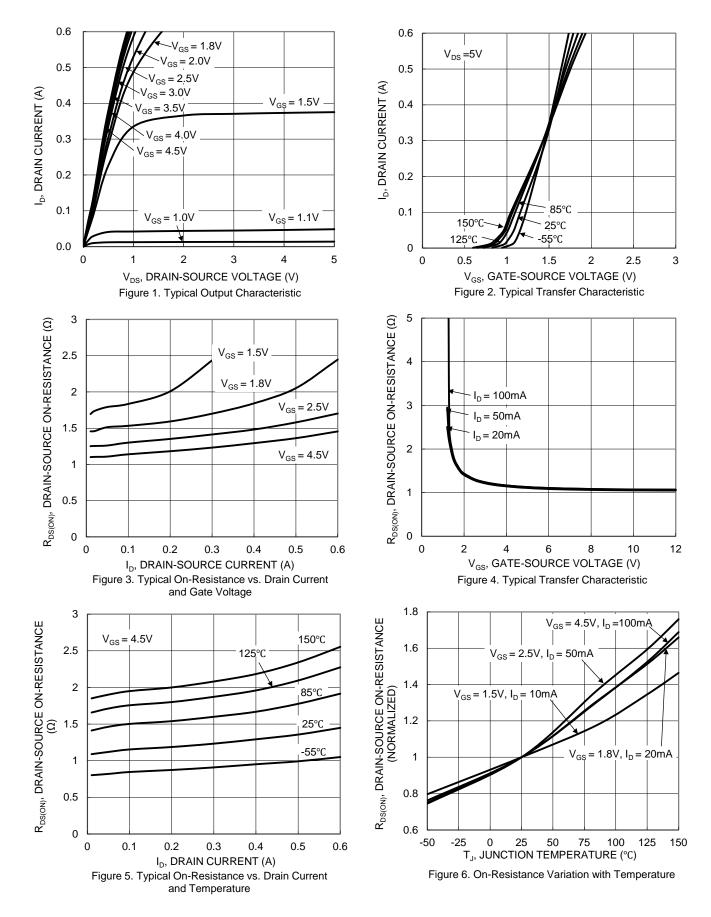
5. Device mounted on FR-4 PCB, with minimum recommended pad layout. Notes:

6. Device mounted on minimum recommended pad layout test board, 10µs pulse duty cycle = 1%.

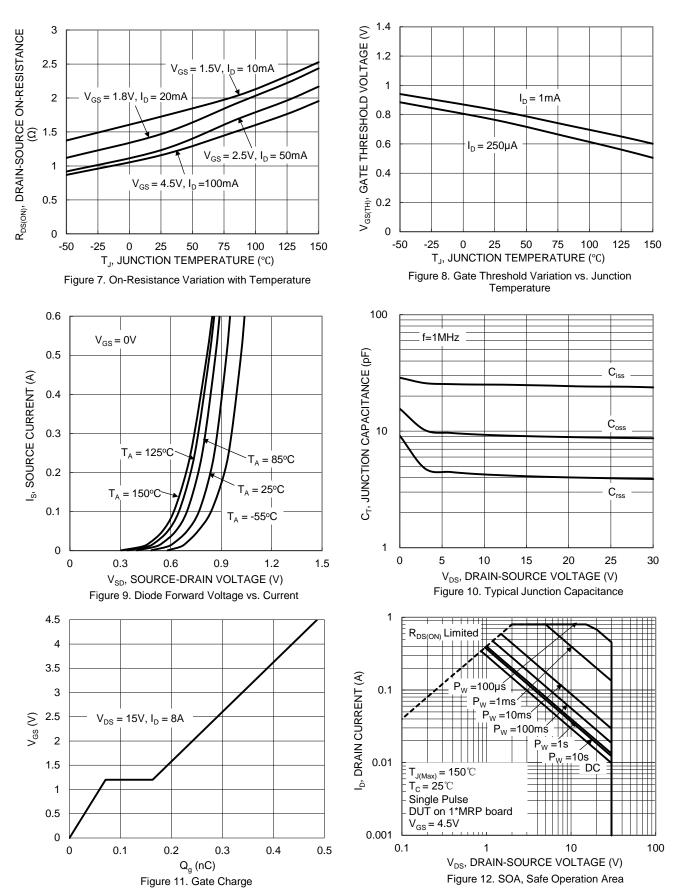
7. Short duration pulse test used to minimize self-heating effect.
 8. Guaranteed by design. Not subject to product testing.

DMN31D5UDAQ



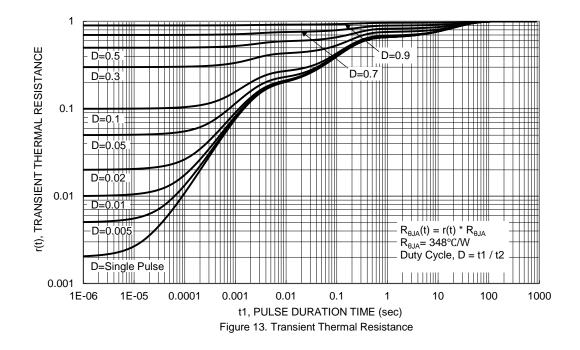






DMN31D5UDAQ Document number: DS42857 Rev. 2 - 2

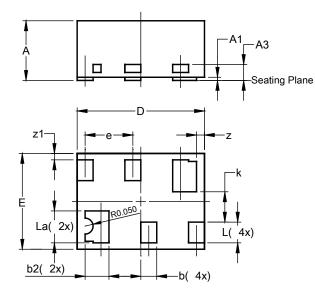






Package Outline Dimensions

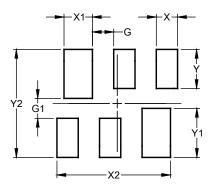
Please see http://www.diodes.com/package-outlines.html for the latest version.



| | X2-DFN0806-6 | | | | | |
|-----|----------------------|------|------|--|--|--|
| Dim | Min | Max | Тур | | | |
| Α | | 0.40 | 0.36 | | | |
| A1 | 0.00 | 0.03 | 0.02 | | | |
| A3 | | | 0.10 | | | |
| b | 0.07 | 0.15 | 0.10 | | | |
| b2 | 0.10 | 0.20 | 0.15 | | | |
| D | 0.75 | 0.85 | 0.80 | | | |
| Е | 0.55 | 0.65 | 0.60 | | | |
| е | | | 0.30 | | | |
| k | | | 0.19 | | | |
| L | 0.10 | 0.18 | 0.13 | | | |
| La | 0.17 | 0.25 | 0.20 | | | |
| z | | | 0.05 | | | |
| z1 | | | 0.04 | | | |
| All | All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| G | 0.150 |
| G1 | 0.140 |
| Х | 0.150 |
| X1 | 0.200 |
| X2 | 0.800 |
| Y | 0.275 |
| Y1 | 0.345 |
| Y2 | 0.760 |



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